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- Inputs Are TTL-Voltage Compatible
- EPIC[™] (Enhanced-Performance Implanted CMOS) Process
- Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

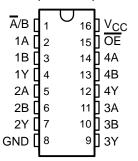
description

These quadruple 2-line to 1-line data selectors/multiplexers are designed for 4.5-V to 5.5-V V_{CC} operation.

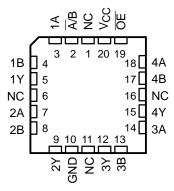
The 'AHCT258 are designed to multiplex signals from 4-bit data sources to 4-output data lines in bus-organized systems. The 3-state outputs do not load the data lines when the output-enable (\overline{OE}) input is at the high logic level.

The SN54AHCT258 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74AHCT258 is characterized for operation from -40°C to 85°C.

SN54AHCT258...J OR W PACKAGE SN74AHCT258...D, DB, N, OR PW PACKAGE (TOP VIEW)



SN54AHCT258...FK PACKAGE (TOP VIEW)



NC - No internal connection

FUNCTION TABLE

	INPUTS					
OE	Ā/B	Α	В	Υ		
Н	Х	Χ	Х	Z		
L	L	L	Χ	Н		
L	L	Н	Χ	L		
L	Н	Χ	L	Н		
L	Н	Χ	Н	L		



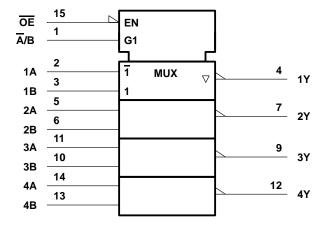
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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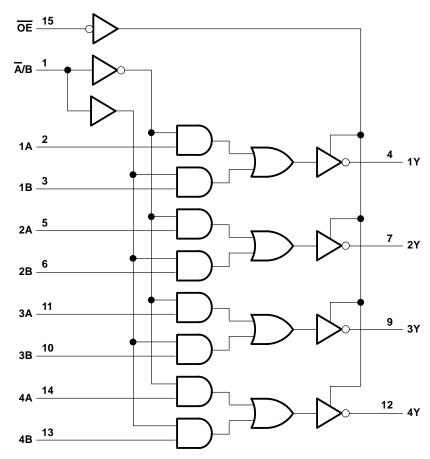
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logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, DB, J, N, PW, and W packages.

logic diagram (positive logic)



Pin numbers shown are for the D, DB, J, N, PW, and W packages.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}		–0.5 V to 7 V
Input voltage range, V _I (see Note 1)		–0.5 V to 7 V
Output voltage range, VO (see Note 1)		0.5 V to V _{CC} + 0.5 V
Input clamp current, $I_{ K }(V_{ I } < 0)$		—20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CO}	c)	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})		±25 mA
Continuous current through V _{CC} or GND		±50 mA
Package thermal impedance, θ_{JA} (see Note 2):	: D package	113°C/W
•	DB package	131°C/W
	N package	
	PW package	149°C/W
Storage temperature range, T _{stg}		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

recommended operating conditions (see Note 3)

		SN54AHCT258		SN54AHCT258 SN74AHCT258		UNIT
		MIN	MAX	MIN	MAX	CIVIT
Vсс	Supply voltage	4.5	5.5	4.5	5.5	V
VIH	High-level input voltage	2		2		V
VIL	Low-level input voltage		0.8		0.8	V
٧ _I	Input voltage	0	5.5	0	5.5	V
٧o	Output voltage	0	VCC	0	VCC	V
IOH	High-level output current		-8		-8	mA
loL	Low-level output current		8		8	mA
Δt/Δν	Input transition rise or fall time		20		20	ns/V
T _A	Operating free-air temperature	– 55	125	-40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T _A = 2		λ = 25°C	= 25°C		SN54AHCT258		SN74AHCT258	
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
\/a	I _{OH} = -50 μA	451/	4.4	4.5		4.4		4.4		.,
Voн	I _{OH} = -8 mA	4.5 V	3.94			3.8		3.8		٧
V	I _{OL} = 50 μA	451/			0.1		0.1		0.1	V
VOL	V_{OL} $I_{OL} = 8 \text{ mA}$ 4.5 V	4.5 V			0.36		0.44		0.44	٧
lį	V _I = V _{CC} or GND	5.5 V			±0.1		±1		±1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40	μΑ
∆lcc [‡]	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5		1.5	mA
loz	$V_O = V_{CC}$ or GND	5.5 V			±0.25		±2.5		±2.5	μΑ
C _i	$V_I = V_{CC}$ or GND	5 V		2	10				10	pF

[‡] This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.



^{2.} The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

			TO LOAD (OUTPUT) CAPACITANCE	SN54AHCT258					
PARAMETER	FROM (INPUT)			T _A = 25°C			MIN	MAX	UNIT
	(01)	(0011 01)	OAI AOITANOL	MIN	TYP	MAX	IVIIIV	IVIAA	
tPLH*	A or B	Y	C _L = 15 pF		4.1	6.4	1	7.5	ns
tpHL*	AUID	•	OL = 13 pi		4.1	6.4	1	7.5	113
tPLH*	Ā/B	Y	C _L = 15 pF		5.3	8.1	1	9.5	ns
tPHL*	A/B	•	OL = 13 pr		5.3	8.1	1	9.5	115
^t PZH*	<u>OE</u>	Y	C _I = 15 pF		5.6	8.6	1	10	ns
^t PZL*	OE	•	OL = 13 pi		5.6	8.6	1	10	113
^t PHZ*	<u>OE</u>	Y	C _I = 15 pF						ns
tPLZ*	OE	•	OL = 13 pi						113
^t PLH	A or B	Y	C _L = 50 pF		5.6	8.4	1	9.5	ns
t _{PHL}		•	OL = 30 pi		5.6	8.4	1	9.5	113
^t PLH	Ā/B	Y	C _L = 50 pF		6.8	10.1	1	11.5	ns
^t PLH	A/B		OL = 30 pi		6.8	10.1	1	11.5	113
^t PZH	<u>OE</u>	Y	C _I = 50 pF		7.1	10.6	1	12	ns
^t PZL	UE .	1	OL = 30 bi		7.1	10.6	1	12	113
^t PHZ	ŌĒ	Y	C _L = 50 pF			·			ns
tPLZ	OE .	1	OL = 30 PF						119

^{*} On products compliant to MIL-PRF-38535, this parameter is ensured but not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

		TO 104D		SN74AHCT258						
PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C			MIN	MAX	UNIT	
	(01)	(0011 01)		MIN	TYP	MAX	IVIIIV	WAX		
^t PLH	A or B	Y	C _L = 15 pF		4.1	6.4	1	7.5	ns	
^t PHL	AOIB	1	OL = 13 pi		4.1	6.4	1	7.5	115	
t _{PLH}	Ā/B	Y	C _L = 15 pF		5.3	8.1	1	9.5	ns	
tPHL	A/B	ı	CL = 15 pr		5.3	8.1	1	9.5	115	
^t PZH		Y	C 15 pE		5.6	8.6	1	10	ns	
^t PZL	ŌĒ		C _L = 15 pF	CL = 15 pr	OL = 15 pr		5.6	8.6	1	10
t _{PHZ}	ŌĒ	Y	C _I = 15 pF						ns	
^t PLZ	OE	1	OL = 13 bi						113	
^t PLH	A or B	Y	C _L = 50 pF		5.6	8.4	1	9.5	ns	
^t PHL	AOID	'	OL = 30 pi		5.6	8.4	1	9.5	113	
^t PLH	Ā/B	Y	C _L = 50 pF		6.8	10.1	1	11.5	ns	
^t PLH	A/B	1	OL = 30 pr		6.8	10.1	1	11.5	115	
^t PZH	ŌĒ	Y	C _L = 50 pF		7.1	10.6	1	12	ns	
^t PZL	OE	1	OL = 30 pr		7.1	10.6	1	12	115	
^t PHZ	ŌĒ	V 0: 50 m	oe y	C _L = 50 pF		•			·	ns
t _{PLZ}	OE .	1	OL = 30 pr						115	



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noise characteristics $V_{CC} = 5 \text{ V}$, $C_L = 50 \text{ pF}$, $T_A = 25^{\circ}\text{C}$ (see Note 4)

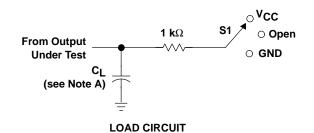
	PARAMETER			UNIT
	FARAMETER	MIN	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.8	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.8	V
VOH(V)	Quiet output, minimum dynamic VOH			V
VIH(D)	High-level dynamic input voltage	2		V
V _{IL(D)}	Low-level dynamic input voltage		0.8	V

NOTE 4: Characteristics are determined during product characterization and ensured by design for surface-mount packages only.

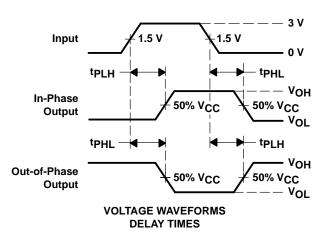
operating characteristics, V_{CC} = 5 V, T_A = 25°C

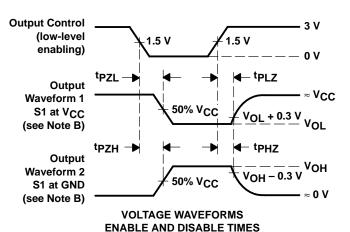
	PARAMETER		ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	20	pF

PARAMETER MEASUREMENT INFORMATION



TEST	S1
tPLH/tPHL	Open
tPLZ/tPZL	VCC
tPHZ/tPZH	GND





NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f = 3 \text{ ns}$, $t_f = 3 \text{ ns}$.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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